

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: Unknown

Inventor: Ren-Guey Hsieh

Serial No. To Be Assigned

Filed: Filed Herewith

For: Gap Forming Pattern Fracturing Method For Forming  
Optical Proximity Corrected Masking Layer

Attorney Docket No.: 67,200-447

2/105  
PD  
9/24/031046 U.S. PTO  
09/975855DISCLOSURE STATEMENT  
UNDER 37 C.F.R. § 1.56Assistant Commissioner  
for Patents  
Washington, D.C. 20231

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Sir:

In compliance with 37 C.F.R. § 1.56, the art listed and identified on the attached Form PTO-1449 is being submitted herewith for consideration by the Examiner. A copy of each of the listed references is included herewith.

It is Applicant's opinion that the claims presently on file patentably distinguish the present invention from each of these references. The above references are being cited only in the interests of candor and without any admission that they constitute statutory prior art or contain matter which anticipates the invention or which would render the same obvious, either singly or in combination, to a person of ordinary skill in the art.

Respectfully submitted,

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